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## Surface Science



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## <sup>1</sup> Atomic layer deposition of enantioselective thin film of alumina on

### <sup>2</sup> chiral self-assembled-monolayer

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#### 5 article info 6

#### **ABSTRACT**

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11 Chiral self-assembled monolayers<br>  $12$  Al<sub>2</sub>O<sub>2</sub>

 $Al<sub>2</sub>O<sub>3</sub>$ 

 $2<sub>2</sub>$ 23

In this paper, we describe the synthesis of new chiral nanosized surfaces based on chiral self-assembled mono- 13 layers coated with metal oxide ( $Al_2O_3$ ) nanolayers. In this new type of nanosized chiral surface, the  $Al_2O_3$  14 nanolayers enable the protection of the chiral self-assembled monolayers while preserving their enantioselective 15 nature. The chiral nature of the SAMs/Al<sub>2</sub>O<sub>3</sub> films was characterized by a variety of techniques, such as, quartz 16 crystal microbalance, circular dichroism (CD) spectroscopy and chiral crystallization. The proposed methodology 17 for the preparation of nanoscale chiral surfaces described in this article could open up opportunities in other 18 fields of chemistry, such as chiral catalysis. 19

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#### 25 1. Introduction

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IN F 0 A B S T R A C T<br>
In this paper we describe the symbolic of the child procedure of the symbolic control bure**  In recent years, chirality at the nanoscale [1–4] and chiral surfaces [5–[14\]](#page--1-0) have been found to play an important role in nanotechnology, particularly chiral nanoscale surfaces and chiral nanoparticles. Generally, chiral solid surfaces can be derived from chiral bulk structures that expose chiral, enantioselective surfaces, such as quartz and other crystalline materials (typically covalent inorganic oxides) [15]. Another category of chiral solid surfaces is composed of crystalline solids pro- duced from materials with achiral bulk structures. Such chiral surfaces are based on single crystals of metals (with bcc or hcp crystal structures) [\[7\]](#page--1-0) that expose high Miller indices with periodic arrays of steps, terraces, and kinks. Finally, the most common method for the preparation of chi- ral surfaces is the adsorption of chiral molecules, typically onto metallic surfaces. The resulting surface is chiral if the adsorbed molecules retain their chirality. Although chiral surfaces based on self-assembled mono- layers (SAMs) or polymeric surfaces exhibit highly enantiospecific prop- erties, they still suffer from many restrictions, such as low thermal stability and poor chemical and mechanical characteristics, which limit their use for chemical applications, particularly for enantioselective ca-talysis and chiral separation.

 In our previous research we proposed an innovative type of stable nanosized chiral metal oxide surface [\[16\].](#page--1-0) The structure and chirality of this type of chiral surface is based on chiral self-assembled mono- layers (SAMs) coated with nanosized films of metal oxide materials (e.g. TiO<sub>2</sub>). In [Fig. 1](#page-1-0) the overall design and synthetic paths for this chiral SAM/metal oxide surface are shown. The fundamental principle of design of these chiral surfaces is that the metal oxide nanolayers coating the chiral SAMs protect the chiral SAMs that would otherwise be destroyed under severe reaction conditions, while preserving their enantioselectivity [\[14\].](#page--1-0)

Our working hypothesis, that it is feasible to design chiral surfaces 55 based on a chiral SAM/metal oxide nanolayer hybrid system, is support- 56 ed by our previous research [16,17] and that of other research groups 57 [18,19] who showed that chirality can be templated in metal oxides to 58 form chiral materials, such as nanoporous alumina nanofilms and meso- 59 porous silica chiral structures. The first demonstration of the prepara- 60 tion of chiral metal oxide surfaces was reported by the Switzer group 61 [20]. In a series of articles [20–22] they showed that chiral surfaces of 62 CuO can be electrodeposited onto achiral substrates (e.g., gold) using 63 solution-templating agents, such as tartaric acid and amino acids, to di- 64 rect the chiral growth of the metal oxide surfaces. 65

In our previous paper [16], we described the development of 66 this innovative type of chiral hybrid surface, based on chiral self- 67 assembled monolayers of cysteine coated with  $TiO<sub>2</sub>$  nanolayers, and 68 demonstrated its chiral nature using various analytical techniques, 69 such as quartz crystal microbalance, second-harmonic generation circu- 70 lar dichroism (SHG-CD), circular dichroism spectroscopy, and chiral 71 crystallization. The contraction of the contraction

Generally, many inorganic metal oxides, such as silica, zeolite, alumi- 73 na, zirconia, ZnO, clay, and others, can be used as supports for chiral 74 SAMs. In this paper we extend our research and demonstrate the basic 75 principle of this type of chiral hybrid surface for other chemical systems. 76 We decided to use  $Al_2O_3$  monolayers to form protective layers on the 77 chiral SAMs, mainly because the atomic layer deposition synthesis of 78  $Al<sub>2</sub>O<sub>3</sub>$  does not require high temperature processing that could harm  $79$ the chiral SAMs. Various growth techniques can be applied to synthesize 80 ceramic nanolayers on chiral SAMs such as vacuum-based methods 81 including chemical vapor deposition (CVD) and metal organic CVD 82 (MOCVD), or chemical solution methods including sol–gel, electro- 83 chemical deposition, and hydrothermal synthesis. However, in this 84 work we utilize the atomic layer deposition (ALD) technique [\[23,24\]](#page--1-0) 85

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Fig. 1. Illustration of the design and the synthesis paths for the new chiral SAMs/metal oxide surfaces.

86 since it provides excellent thickness control and produces very dense 87 and uniform layers.

#### 88 2. Material and methods

89 Gold films were deposited on mica,  $KAI<sub>2</sub>(AISi<sub>3</sub>O<sub>10</sub>)(OH)<sub>2</sub>$ . Typically, a 50 nm thick layer of gold (99.995%) was sputtered on freshly cleaved 91 mica sheets at a pressure of approximately  $1 \times 10^{-3}$  mbar with a depo-92 sition rate of 0.5 nm s $^{-1}$ . Chiral SAMs were formed on the gold surfaces by immersing the gold substrates overnight in 10 mM solutions of D, L-cysteine or L-glutathione (Fig. S1) in deionized water. After removal from the solutions, the chiral SAMs surfaces were washed thoroughly with water and blown dry with nitrogen.

#### 97 2.1. Atomic layer deposition (ALD)

98 The samples were introduced into the ALD system (Cambridge, Fiji 99 F200). The Al<sub>2</sub>O<sub>3</sub> thin films were deposited onto chiral SAMs surfaces 100 using a  $AI(CH_3)_3$  precursor and water. Ar served as both the carrier 101 and the purging gas. Thin films of  $Al_2O_3$  were grown on the chiral 102 SAMs at 373 K under  $1 \times 10^{-2}$  Torr. The ALD cycle consisted of 0.06 s 103 exposure to  $Al(CH_3)_3$  (evaporated at 348 K), 10 s Ar purge, and a 104 0.06 s exposure to water. A total of 130 ALD cycles were used to obtain  $105$  Al<sub>2</sub>O<sub>3</sub> films with a thickness of 8.9 nm.

106 2.2. High-resolution transmission electron microscope (HR-TEM)

107 Images were taken with a 2100 JEOL microscope working at a volt-108 age of 200 kV and were recorded on a CCD  $4 \times 4$  k camera (Gatan). 109 EDS chemical analysis was performed with a Thermo electron group 110 system.

111 2.3. X-ray photoelectron spectroscopy analysis (XPS)

 XPS analyses were performed in a Kratos AXIS-HS spectrometer, 113 using a monochromatized  $AI_{K\alpha}$  source. Survey and high resolution spec- tra were acquired at 75 or 150 W, respectively. All data acquisitions were performed at detection pass energies of 40–80 eV. All XPS mea- surements were carried out at room temperature, under vacuum condi-117 tions of (1.0–3.0)  $10^{-9}$  Torr. Spectra were acquired with a low electron flood gun for charge neutralization. The spectrometer energy scale was routinely calibrated according to the ISO TC/201 SC7 international pro- cedure for binding energy (BE) with Au 4f 7/2 83.98 and Cu 2p 3/2 932.67. Spectra binding energy were not corrected for charging shifts. 122 Data processing was done with VISION software (Kratos).

123 2.4. Quartz crystal microbalance (QCM)

 Changes in the resonance frequency as a result of adsorption pro- cesses on the sensor electrode were monitored by a SRS QCM 200 sen- sor (Stanford Research Systems, Sunnyvale, USA) system. AT-cut quartz crystals with gold electrodes and a fundamental oscillating frequency of 5 MHz (Stanford Research Systems, Inc.) were used as sensing sub-strates. The sampling period and the resolution of the frequency counter were 1 s and 0.1 Hz respectively. All the measurements were done at 130 room temperature. 131

2.5. Circular dichroism (CD) 132

CD spectra were recorded on a Chirascan CD spectrometer (Applied 133 Photophysics) using a bandwidth of 1 nm, from 600 to 350 nm. The step 134 size and time were set at 1 nm and 0.5 s respectively. During the CD 135 measurement, each surface was rotated in 90° intervals from 0° to 270°. 136

2.6. Enantioselective crystallization 137

enent unicaties control anti produces very dense were to since the spectroes. The the spectroscopy and the spectroscopy and the spectroscopy and the spectroscopy and gald (99.995%) was sputtered on feesibly cleaved. The p In all crystallization experiments, analytical grade amino acids 138  $(>99.9%)$  were purchased from Sigma Aldrich and used as received. 139 The experiments were conducted with supersaturated solutions of 140 DL-threonine (7.5 g) and DL-valine (2.875 g) in deionized water 141 (25 ml). Thereafter, the solutions were heated to 75 °C and stirred 142 until they were completely dissolved and left to cool to room tempera- 143 ture. Finally, the chiral surfaces were placed vertically in the crystalliza- 144 tion solutions. Macrosized crystals crystallized at the chiral surfaces 145 were detected and removed manually from the chiral surfaces; the 146 enantiomeric excess (ee) in both crystals crystallized on the surfaces 147 and bulk crystallization solutions were measured separately, in order 148 to determine the amount of chiral separation. Specific light rotation 149 was measured with a JASCO digital polarimeter (Model P-1010 150  $\lambda = 589$  nm,  $\pm 0.05^{\circ}$  accuracy) using a cylindrical quartz cell (10 mL, 151)  $L = 100$  mm) at room temperature by dissolving the crystals in water. 152

#### **3. Results and discussion 153**

The first step in the synthesis of this type of nanochiral surface re- 154 quires the preparation of chiral SAMs. Generally, chiral SAMs can be 155 produced by reacting gold substrates with thiols that feature chiral 156 groups at the tail terminus. Gold films of 50 nm thickness were deposit- 157 ed on mica substrates using a high-vacuum sputtering technique. AFM 158 measurements of the gold films show very smooth films with an aver- 159 age root–mean–square (RMS) roughness of 5 Å and typical gold grain  $160$ sizes of 60 nm [16]. X-ray diffraction measurements of the gold films in- 161 dicate strong orientation of the gold films along the (111) crystal plane 162 [16]. 163

For the chiral SAMs, we used enantiomers of cysteine and glutathi- 164 one. The chiral SAMs were formed on the gold surfaces by immersing 165 the gold substrates in 10 mM solutions of cysteine or glutathione in 166 water overnight. The formation and structure of the chiral SAMs on 167 the gold surfaces were verified using various techniques. X-ray photo- 168 electron spectroscopy (XPS) of the chiral SAMs on the gold surface 169 shows typical Au 4f (81 eV), N 1 s (398 eV), and C 1 s (282 eV) peaks. 170 In addition, the sulfur (S 2p) peak seen at 159 eV is attributed to the 171 S–Au bond. Finally, contact angle measurements of the bare gold (con- 172 tact angle of 67°) and of the D or L-cysteine SAMs (contact angle of 18° 173 and full spread for glutathione) indicated the formation of homogenous 174 self-assembled monolayers on the gold surfaces. 175

Al<sub>2</sub>O<sub>3</sub> films were grown by ALD using Al(CH<sub>3</sub>)<sub>3</sub> as the precursor, fol- 176 lowing the process described previously [\[25\].](#page--1-0) Briefly, films were grown 177

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